

<b>SANYO</b>	No.5032	<b>2SC5226</b>
		NPN Epitaxial Planar Silicon Transistor VHF to UHF Wide-Band Low-Noise Amp Applications

**Features**

- Low noise :  $NF = 1.0\text{dB typ (} f = 1\text{GHz)}$ .
- High gain :  $|S_{21e}|^2 = 12\text{dB typ (} f = 1\text{GHz)}$ .
- High cutoff frequency :  $f_T = 7\text{GHz typ}$ .

**Absolute Maximum Ratings at  $T_a = 25^\circ\text{C}$**

			unit
Collector-to-Base Voltage	$V_{CB0}$	20	V
Collector-to-Emitter Voltage	$V_{CE0}$	10	V
Emitter-to-Base Voltage	$V_{EB0}$	2	V
Collector Current	$I_C$	70	mA
Collector Dissipation	$P_C$	150	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

**Electrical Characteristics at  $T_a = 25^\circ\text{C}$**

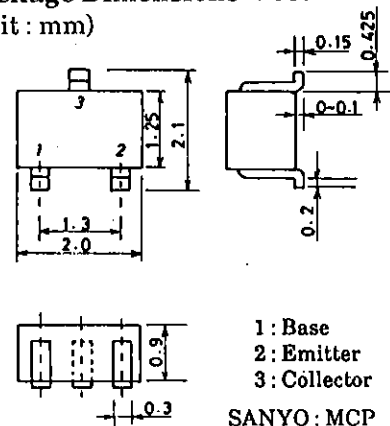
			min	typ	max	unit
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = 10\text{V}, I_E = 0$			1.0	$\mu\text{A}$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = 1\text{V}, I_C = 0$			10	$\mu\text{A}$
DC Current Gain	$h_{FE}$	$V_{CE} = 5\text{V}, I_C = 20\text{mA}$	60*		270*	
Gain-Bandwidth Product	$f_T$	$V_{CE} = 5\text{V}, I_C = 20\text{mA}$	5	7		GHz
Output Capacitance	$C_{ob}$	$V_{CB} = 10\text{V}, f = 1\text{MHz}$		0.75	1.2	pF
Reverse Transfer Capacitance	$C_{re}$	$V_{CB} = 10\text{V}, f = 1\text{MHz}$		0.5		pF
Forward Transfer Gain	$ S_{21e} ^2(1)$	$V_{CE} = 5\text{V}, I_C = 20\text{mA}, f = 1\text{GHz}$	9	12		dB
	$ S_{21e} ^2(2)$	$V_{CE} = 2\text{V}, I_C = 3\text{mA}, f = 1\text{GHz}$		8		dB
Noise Figure	NF	$V_{CE} = 5\text{V}, I_C = 7\text{mA}, f = 1\text{GHz}$	1.0	1.8		dB

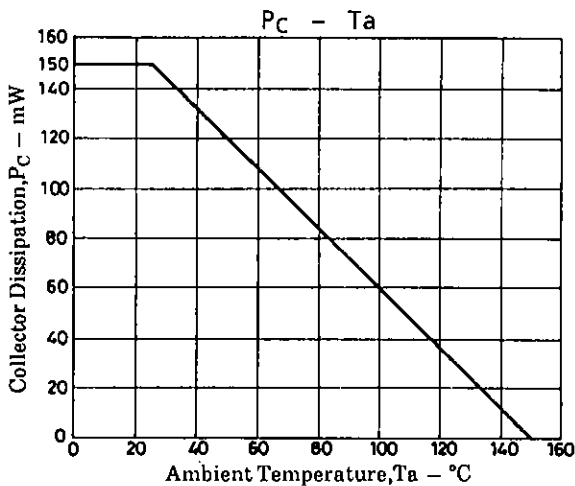
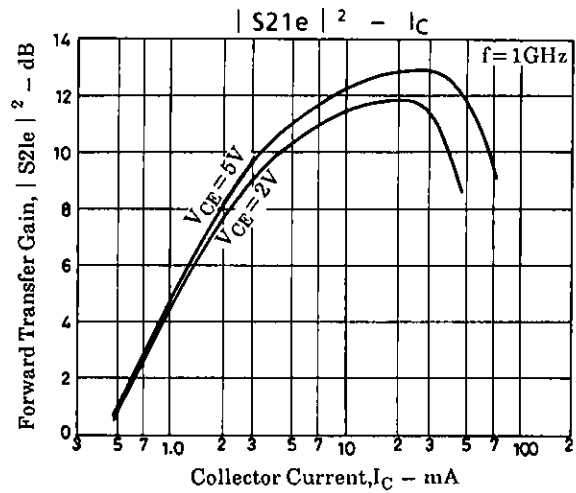
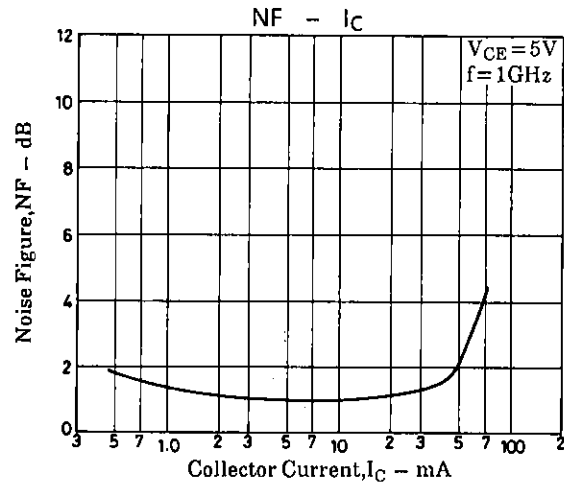
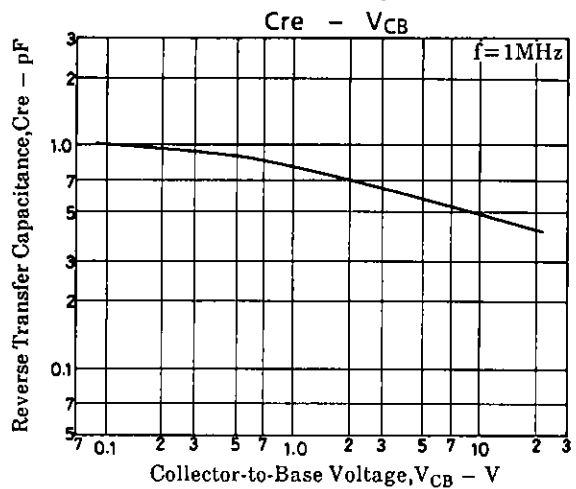
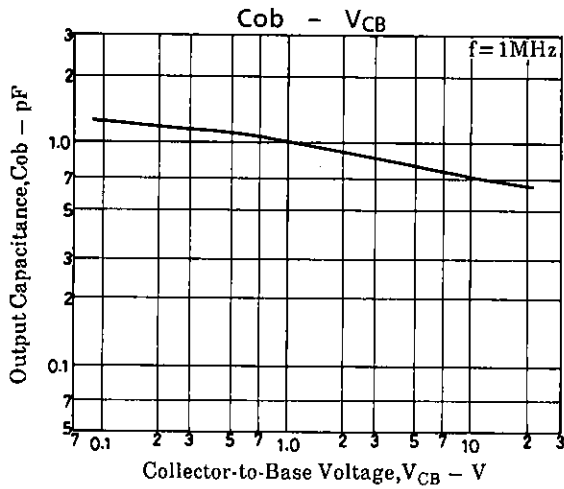
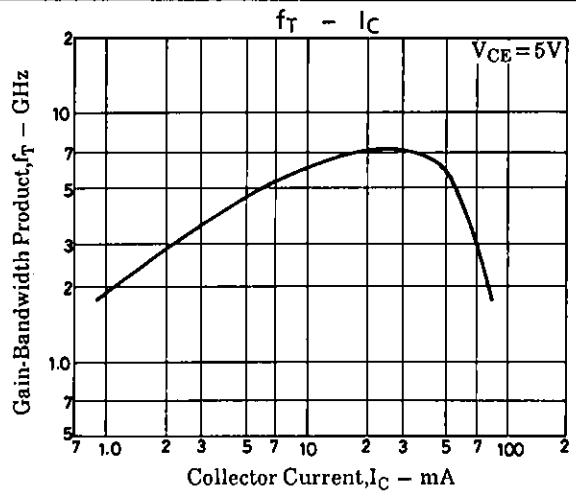
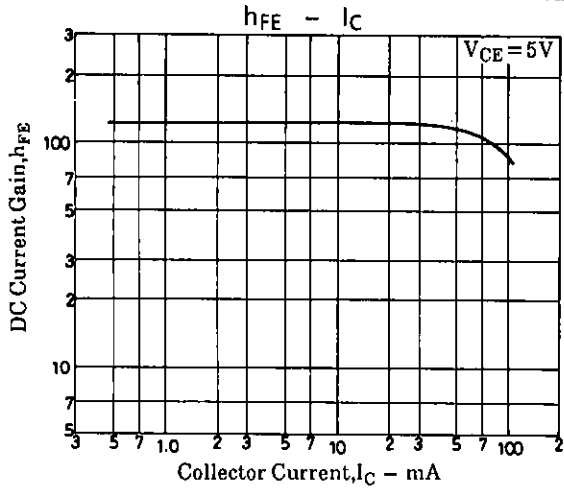
\* : The 2SC5226 is classified by 20mA  $h_{FE}$  as follows :

60	3	120	90	4	180	135	5	270
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Marking : LN  
 $h_{FE}$  rank : 3, 4, 5

**Package Dimensions 2059A**  
(unit : mm)

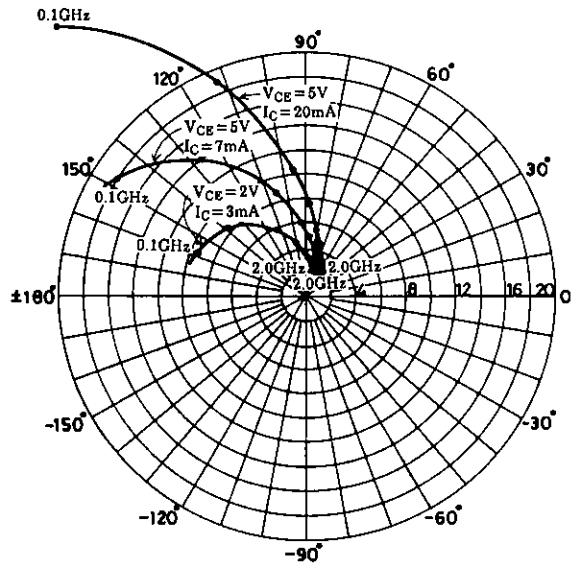
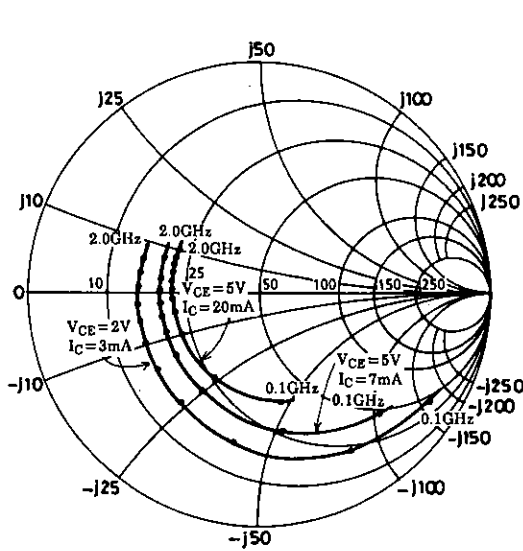




**S Parameter**

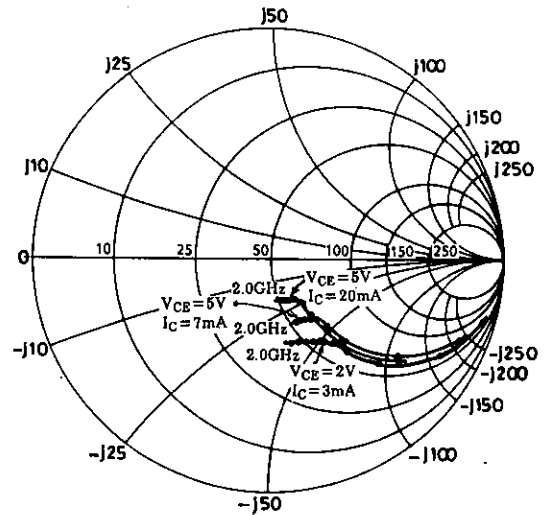
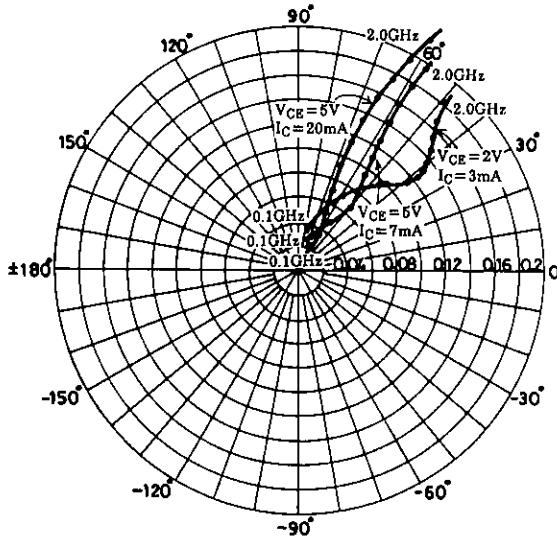
f = 100MHz, 200 to 2000MHz (200MHz step)

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## S Parameter (Common emitter)

 $V_{CE}=5V, I_C=7mA, Z_0=50\Omega$ 

Freq (MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
100	0.720	-46.0	17.973	148.5	0.030	68.5	0.880	-23.6
200	0.612	-80.9	13.927	127.3	0.047	57.1	0.697	-37.6
400	0.497	-121.3	8.656	105.0	0.066	51.3	0.479	-47.6
600	0.456	-143.5	6.080	92.8	0.079	52.9	0.382	-50.5
800	0.440	-157.6	4.725	84.3	0.094	55.4	0.339	-51.8
1000	0.436	-167.5	3.864	77.0	0.110	56.8	0.323	-53.4
1200	0.434	-176.1	3.258	70.3	0.126	57.9	0.312	-55.8
1400	0.433	176.6	2.847	64.5	0.143	58.4	0.304	-58.3
1600	0.433	170.9	2.329	57.4	0.160	58.9	0.296	-62.0
1800	0.434	165.0	2.252	54.2	0.178	58.6	0.293	-65.0
2000	0.439	159.6	2.057	49.2	0.197	58.1	0.294	-68.1

 $V_{CE}=5V, I_C=20mA, Z_0=50\Omega$ 

Freq (MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
100	0.481	-78.8	29.795	132.9	0.022	63.9	0.707	-38.2
200	0.420	-119.2	19.008	112.2	0.033	60.8	0.470	-51.1
400	0.391	-151.6	10.416	95.4	0.052	64.7	0.296	-55.3
600	0.386	-166.4	7.084	86.6	0.071	67.2	0.236	-56.1
800	0.381	-175.9	5.407	80.1	0.092	68.4	0.213	-56.6
1000	0.382	178.2	4.401	74.1	0.114	67.8	0.208	-57.9
1200	0.385	172.1	3.701	68.5	0.134	66.8	0.204	-60.7
1400	0.388	166.7	3.217	63.6	0.156	65.6	0.202	-63.5
1600	0.390	162.1	2.839	58.8	0.176	64.0	0.199	-67.9
1800	0.391	156.7	2.534	54.3	0.197	62.4	0.197	-71.2
2000	0.394	152.1	2.319	50.1	0.219	60.6	0.197	-74.2

 $V_{CE}=2V, I_C=3mA, Z_0=50\Omega$ 

Freq (MHz)	$ S_{11} $	$\angle S_{11}$	$ S_{21} $	$\angle S_{21}$	$ S_{12} $	$\angle S_{12}$	$ S_{22} $	$\angle S_{22}$
100	0.858	-32.4	9.413	157.2	0.040	72.6	0.945	-16.5
200	0.782	-60.7	8.187	138.5	0.070	59.2	0.833	-29.3
400	0.653	-101.1	5.855	113.8	0.101	44.5	0.637	-43.2
600	0.588	-126.5	4.337	98.4	0.114	39.1	0.515	-50.0
800	0.557	-143.7	3.444	87.7	0.122	38.0	0.454	-53.8
1000	0.543	-156.3	2.871	78.5	0.130	38.6	0.426	-57.1
1200	0.536	-166.8	2.446	70.5	0.137	40.3	0.407	-60.3
1400	0.533	-175.5	2.145	63.5	0.146	42.5	0.393	-63.8
1600	0.527	177.0	1.904	57.1	0.155	45.0	0.382	-68.0
1800	0.525	170.3	1.714	51.7	0.168	47.3	0.379	-72.0
2000	0.528	163.8	1.564	45.9	0.183	49.2	0.378	-75.8